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Texas Instruments
CD4066BQDRQ1

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Datasheet of CD4066BQDRQ1 - IC QUAD BILATERAL SWITCH 14SOIC

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CD4066B-Q1

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CMOS QUAD BILATERAL SWITCH

Check for Samples: CD4066B-Q1

FEATURES

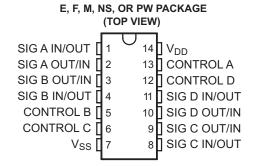
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- Qualified for Automotive Applications
- 15-V Digital or ±7.5-V Peak-to-Peak Switching
- 125-Ω Typical On-State Resistance for 15-V Operation
- Switch On-State Resistance Matched to Within 5 Ω Over 15-V Signal-Input Range
- On-State Resistance Flat Over Full Peak-to-Peak Signal Range
- High On/Off Output-Voltage Ratio: 80 dB Typical at $f_{is} = 10$ kHz, $R_L = 1$ k Ω
- High Degree of Linearity: <0.5% Distortion Typical at f_{is} = 1 kHz, V_{is} = 5 V p-p, V_{DD} − V_{SS} ≥ 10 V, R_L = 10 kΩ
- Extremely Low Off-State Switch Leakage, Resulting in Very Low Offset Current and High Effective Off-State Resistance: 10 pA Typical at V_{DD} - V_{SS} = 10 V, T_A = 25°C
- Extremely High Control Input Impedance (Control Circuit Isolated From Signal Circuit): $10^{12} \Omega$ Typical
- Low Crosstalk Between Switches: –50 dB Typical at f_{is} = 8 MHz, R_L = 1 kΩ
- Matched Control-Input to Signal-Output Capacitance: Reduces Output Signal Transients
- Frequency Response, Switch On = 40 MHz Typical
- 100% Tested for Quiescent Current at 20 V

- 5-V, 10-V, and 15-V Parametric Ratings
- · Latch-Up Exceeds 100mA per JESD78 Class I
- Meets All Requirements of JEDEC Tentative Standard No. 13-B, Standard Specifications for Description of "B" Series CMOS Devices

APPLICATIONS

- Analog Signal Switching/Multiplexing: Signal Gating, Modulator, Squelch Control, Demodulator, Chopper, Commutating Switch
- Digital Signal Switching/Multiplexing
- Transmission-Gate Logic Implementation
- Analog-to-Digital and Digital-to-Analog Conversion
- Digital Control of Frequency, Impedance, Phase, and Analog-Signal Gain



DESCRIPTION/ORDERING INFORMATION

The CD4066B-Q1 is a quad bilateral switch intended for the transmission or multiplexing of analog or digital signals. It is pin-for-pin compatible with the CD4016B, but exhibits a much lower on-state resistance. In addition, the on-state resistance is relatively constant over the full signal-input range.

The CD4066B-Q1 consists of four bilateral switches, each with independent controls. Both the p and the n devices in a given switch are biased on or off simultaneously by the control signal. As shown in Figure 1, the well of the n-channel device on each switch is tied to either the input (when the switch is on) or to VSS (when the switch is off). This configuration eliminates the variation of the switch-transistor threshold voltage with input signal and, thus, keeps the on-state resistance low over the full operating-signal range.

The advantages over single-channel switches include peak input-signal voltage swings equal to the full supply voltage and more constant on-state impedance over the input-signal range. However, for sample-and-hold applications, the CD4016B is recommended.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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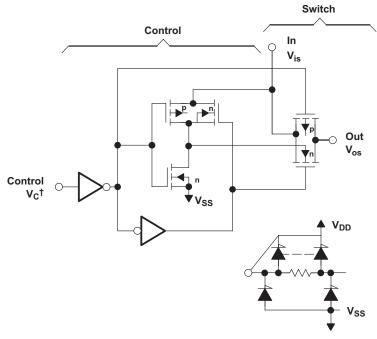
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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ORDERING INFORMATION

T _A	PACI	KAGE	ORDERABLE PART NUMBER	TOP-SIDE MARKING
-40°C to 125°C	SOIC - D	Reel of 2500	CD4066BQDRQ1	CD4066BQ



 † All control inputs are protected by the CMOS protection network.

NOTES: A.All p substrates are connected to V $_{DD}$. B. Normal operation control-line biasing: switch on (logic 1), $V_C = V_{DD}$; switch off (logic 0), $V_C = V_{SS}$

C. Signal-level range: $V_{SS} \le V_{is} \le V_{DD}$

Figure 1. Schematic Diagram of One-of-Four Identical Switches and Associated Control Circuitry

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ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted) (1)

		VALUE	UNIT	
DC supply-voltage range, V _{DD} (voltages	referenced to V _{SS} terminal)	-0.5 to 20	V	
Input voltage range, V _{is} (all inputs)	-0.5 to $V_{DD} + 0.5$	V		
DC input current, IIN (any one input)	±10	mA		
Package thermal impedance, θ _{JA} ⁽²⁾	86	°C/W		
	Human-Body Model (HBM)	500	V	
ESD Electrostatic discharge (3)	Machine Model (MM)	150		
	Field_Induced_Charged Device Model (CDM)	1000		
Lead temperature (during soldering): At	265	°C		
Storage temperature range, T _{stg}	·	-65 to 150	°C	

Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

THERMAL INFORMATION

		CD4066B-Q1	
	THERMAL METRIC ⁽¹⁾	D PACKAGE	UNITS
		14 PINS	
θ_{JA}	Junction-to-ambient thermal resistance	92.4	
θ_{JCtop}	Junction-to-case (top) thermal resistance	52.5	
θ_{JB}	Junction-to-board thermal resistance	46.7	°C/M
ΨЈТ	Junction-to-top characterization parameter	46.4	°C/W
Ψ_{JB}	Junction-to-board characterization parameter	46.4	
θ_{JCbot}	Junction-to-case (bottom) thermal resistance	N/A	

⁽¹⁾ For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.

RECOMMENDED OPERATING CONDITIONS

		MIN	MAX	UNIT
V_{DD}	Supply voltage	3	18	V
T _A	Operating free-air temperature	-40	125	°C

The package thermal impedance is calculated in accordance with JESD 51-7.

Tested in accordance with AEC-Q100.



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ELECTRICAL CHARACTERISTICS

over operating free-air temperature range (unless otherwise noted)

					LIMITS AT IN	NDICATED TEMP	ERATURE	S	
	PARAMETER	TEST CONDITIONS	V _{IN}	V _{DD}	-40°C	125°C	25	°C	UNIT
	PARAMETER	TEST CONDITIONS	(V)	(V)	-40 C	125 C	TYP	MAX	
			0.5	5	0.25	7.5	0.01	0.25	
	Quiescent device current		0.10	10	0.5	15	0.01	0.5	
I _{DD}	Quiescent device current		0.15	15	1	30	0.01	1	μA
			0.20	20	5	150	0.02	5	
SIGNA	AL INPUTS (V _{is}) AND OUTPUT	rs (V _{os})							
		$V_C = V_{DD}$, $R_L = 10 \text{ k}\Omega$ returned		5	850	1300	470	1050	
r _{on}	On-state resistance (max)	V V	10	330	550	180	400	Ω	
·on	on dialo resistante (max)	to $\frac{V_{DD} V_{SS}}{V_{is} = V_{SS} \text{ fo } V_{DD}}$,	15	210	320	125	240	12	
	On-state resistance	$R_L = 10 \text{ k}\Omega, V_C = V_{DD}$					15		Ω
Δr_{on}	difference between any two						10		
	switches		15			5			
THD	Total harmonic distortion	$ \begin{vmatrix} V_C = V_{DD} = 5 \text{ V}, \text{ V}_{SS} = -5 \text{ V}, \\ V_{\text{is(p-p)}} = 5 \text{ V} \text{ (sine wave centered on 0 V),} \\ R_L = 10 \text{ k}\Omega, f_{\text{is}} = 1\text{-kHz sine wave} \\ \end{vmatrix} $				0.4%			
	3-dB cutoff frequency (switch on)	$V_C = V_{DD} = 5 \text{ V}, V_{SS} = -5 \text{ V}, V_{is(p-p)} = 5 \text{ V}$ (sine wave centered on 0 V), $R_L = 1 \text{ k}\Omega$					40		MHz
	-50-dB feedthrough frequency (switch off)	$V_C = V_{SS} = -5 \text{ V}, V_{is(p-p)} = 5 \text{ V}$ (sine wave centered on 0 V), $R_L = 1 \text{ k}\Omega$					1		MHz
I _{is}	Input/output leakage current (switch off) (max)	$V_C = 0 \text{ V}, V_{is} = 18 \text{ V}, V_{os} = 0 \text{ V}; \text{ and } V_C = 0 \text{ V}; V_{is} = 0 \text{ V}, V_{os} = 18 \text{ V}$) V,	18	±0.1	±1	±10 ⁻⁵	±0.1	μΑ
	–50-dB crosstalk frequency	$ \begin{vmatrix} V_{C}(A) = V_{DD} = 5 \text{ V}, \\ V_{C}(B) = V_{SS} = -5 \text{ V}, \\ V_{Is}(A) = 5 \text{ V}_{p-p}, 50 \cdot \Omega \text{ source, } R_{L} = 1 \text{ k}\Omega $					8		MHz
		$R_L = 200 \text{ k}\Omega, V_C = V_{DD}, V_{SS} = GND,$		5			20	40	
t_{pd}	Propagation delay (signal input to signal output)	$C_L = 50 \text{ pF}, V_{is} = 10 \text{ V}$					10	20	ns
		(square wave centered on 5 V), t_r , $t_f = 20 r$	15			7	15		
C_{is}	Input capacitance	$V_{DD} = 5 \text{ V}, V_{C} = V_{SS} = -5 \text{ V}$					8		pF
Cos	Output capacitance	$V_{DD} = 5 \text{ V}, V_{C} = V_{SS} = -5 \text{ V}$					8		pF
C_{ios}	Feedthrough	$V_{DD} = 5 \text{ V}, V_{C} = V_{SS} = -5 \text{ V}$					0.5		pF

Product Folder Link(s): CD4066B-Q1

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ELECTRICAL CHARACTERISTICS (continued)

over operating free-air temperature range (unless otherwise noted)

							ERATURE	S	
	D. D. M. ETED	TEST SOURITIONS	V _{DD}	4000	10500	25°	25°C		
	PARAMETER	TEST CONDITIONS	(V)	–40°C	125°C	TYP	MAX		
CONT	ROL (V _C)								
				5	1	1		1	
V_{ILC}	Control input, low voltage (max)	$ I_{is} $ < 10 mA, $V_{is} = V_{SS}$, $V_{OS} = V_{DD}$, and $V_{is} = V_{DD}$, $V_{OS} = V_{SS}$	10	2	2		2	V	
	(max)	VIS - VDD, VOS - VSS	15	2	2		2		
				5	3.5 (MIN)				
V_{IHC}	Control input, low voltage	See Figure 6			7 (MIN)				
			15		11 (MIN)				
I _{IN}	Input current (max)	$V_{is} \le V_{DD}, V_{DD} - V_{SS} = 18 \text{ V}, V_{CC} \le V_{DD} - V_{CC}$	'ss	18	±0.1	±1	±10 ⁻⁵	±0.1	μA
	Crosstalk (control input to signal output)	V_C = 10 V (square wave), t_r , t_f = 20 ns, R_L = 10 kΩ		10			50		mW
				5			35	70	
	Turn-on and turn-off propagation delay	$V_{IN} = V_{DD}, t_r, t_f = 20 \text{ ns},$ $C_1 = 50 \text{ pF}, R_1 = 1 \text{ k}\Omega$	10			20	40	ns	
	propagation delay	OL = 30 β1 ; INL = 1 KΩ2	15			15	30		
		$V_{is} = V_{DD}, V_{SS} = GND, R_L = 1 \text{ k}\Omega \text{ to GND},$	5			6			
	Maximum control input	$C_L = 50 \text{ pF}, V_C = 10 \text{ V} \text{ (square wave}$	10			9		MHz	
r	repetition rate	centered on 5 V), t_r , t_f = 20 ns, V_{os} = 1/2 V_{os} at 1 kHz	15			9.5			
Ci	Input capacitance						5		pF

SWITCHING CHARACTERISTICS

		SWITCH INPUT						
V _{DD} (V)	V _{is}			Vos	, (V)			
(*)	(V)	-40°C	25°C	125°C	MIN	MAX		
5	0	0.61	0.51	0.36		0.4		
5	5	-0.61	-0.51	-0.36	4.6			
10	0	1.5	1.3	0.9				
10	10	-1.6	-1.3	-0.9				
15	0	4	3.4	2.4		1.5		
15	15	-4	-3.4	-2.4	13.5			

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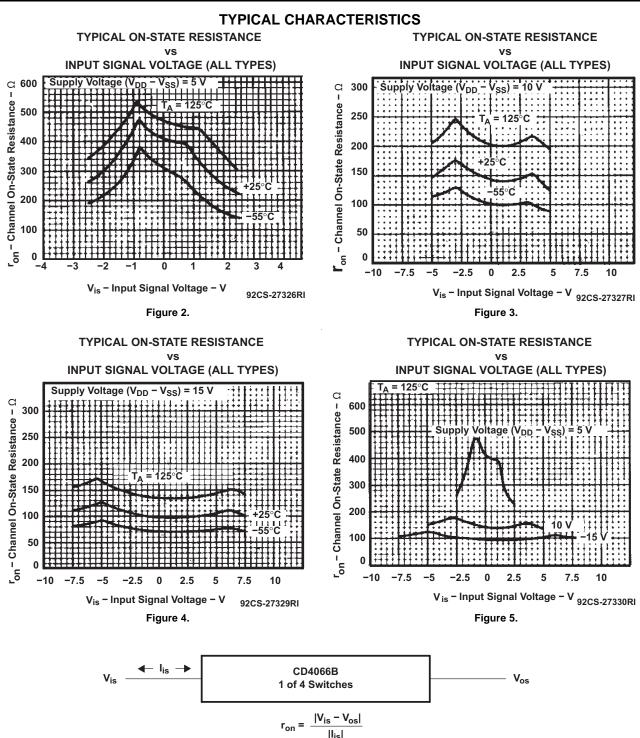


Figure 6. Determination of ron as a Test Condition for Control-Input High-Voltage (VIHC) Specification

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TYPICAL CHARACTERISTICS (continued)

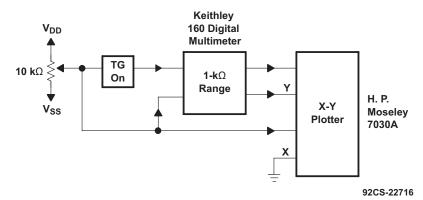


Figure 7. Channel On-State Resistance Measurement Circuit

TYPICAL ON CHARACTERISTICS FOR 1 OF 4 CHANNELS AMBIENT TEMPERATURE(T_A) = 25 °C V_{DO} = 2.5 V, V_{SS} = -2.5 V INPUT = TERM I, OUTPUT = TERM. 2 1 V_C = V_{DD} V_{DD} V_{SS} = -2.5 V V_{SS} = -2.5 V INPUT = TERM I, OUTPUT = TERM. 2 All unused terminals are connected to V_{SS} All unused terminals are connected to V_{SS} All unused terminals are connected to V_{SS} 1 V_I - Input Voltage - V 92CS-30919

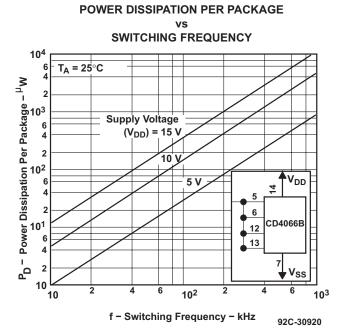


Figure 8.

Figure 9.

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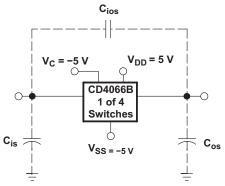
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TYPICAL CHARACTERISTICS (continued)



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All unused terminals are connected to V_{SS}.

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Measured on Boonton capacitance bridge, model 75a (1 MHz); test-fixture capacitance nulled out.

Figure 10. Typical On Characteristics for One of Four Channels

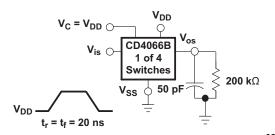
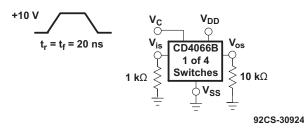


Figure 11. Off-Switch Input or Output Leakage

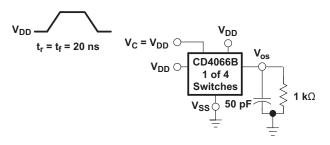


92CS-30923 All unused terminals are connected to V_{SS}.

All unused terminals are connected to $V_{\mbox{\scriptsize SS}}$.

Figure 12. Propagation Delay Time Signal Input (V_{is}) to Signal Output (V_{os})

Figure 13. Crosstalk-Control Input to Signal Output



NOTES: A.All unused terminals are connected to V $\,$ SS.

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B. Delay is measured at V_{os} level of +10% from ground (turn-on) or on-state output level (turn-off).

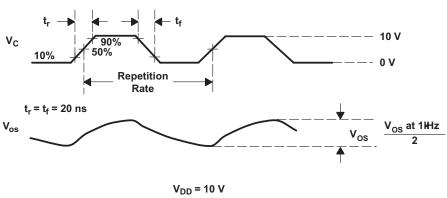
Figure 14. Propagation Delay, t_{PLH} , t_{PHL} Control-Signal Output

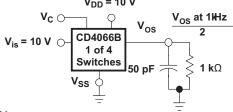


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TYPICAL CHARACTERISTICS (continued)

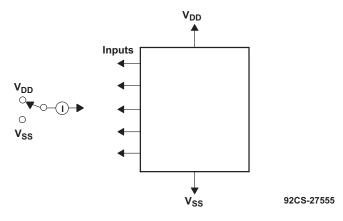




All unused terminals are connected to V_{SS}.

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Figure 15. Maximum Allowable Control-Input Repetition Rate



Measure inputs sequentially to both V_{DD} and V_{SS} . Connect all unused inputs to either V_{DD} or V_{SS} . Measure control inputs only.

Figure 16. Input Leakage-Current Test Circuit

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TYPICAL CHARACTERISTICS (continued)

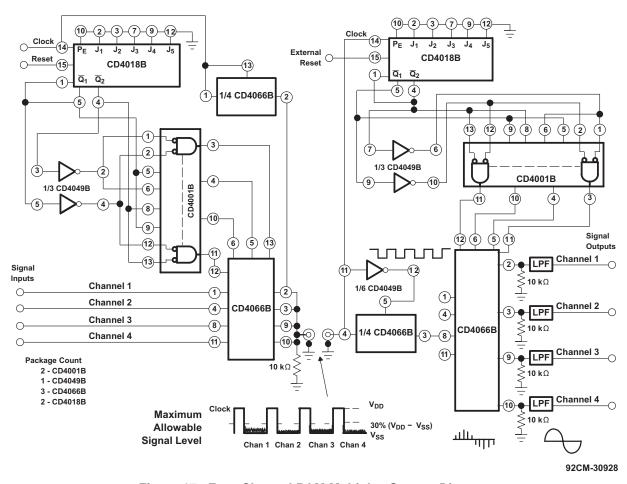


Figure 17. Four-Channel PAM Multiplex System Diagram

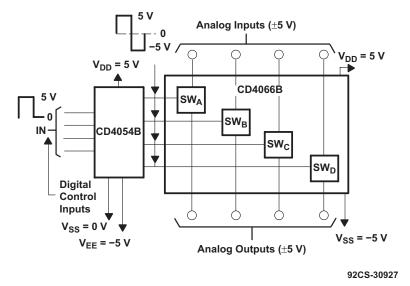


Figure 18. Bidirectional Signal Transmission Via Digital Control Logic

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APPLICATION INFORMATION

In applications that employ separate power sources to drive V_{DD} and the signal inputs, the V_{DD} current capability should exceed V_{DD}/R_L (R_L = effective external load of the four CD4066B-Q1 bilateral switches). This provision avoids any permanent current flow or clamp action on the V_{DD} supply when power is applied or removed from the CD4066B-Q1.

In certain applications, the external load-resistor current can include both V_{DD} and signal-line components. To avoid drawing V_{DD} current when switch current flows into terminals 1, 4, 8, or 11, the voltage drop across the bidirectional switch must not exceed 0.8 V (calculated from r_{on} values shown).

No V_{DD} current will flow through R_L if the switch current flows into terminals 2, 3, 9, or 10.



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PACKAGE OPTION ADDENDUM

11-Apr-2013

PACKAGING INFORMATION

Orderable Device	Status	Package Type	•	Pins	•	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
	(1)		Drawing		Qty	(2)		(3)		(4)	
CD4066BQDRQ1	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	CD4066BQ	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design. PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details. **TBD:** The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): Tl's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between

the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

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OTHER QUALIFIED VERSIONS OF CD4066B-Q1:

Catalog: CD4066B



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PACKAGE OPTION ADDENDUM

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Military: CD4066B-MIL

NOTE: Qualified Version Definitions:

Catalog - TI's standard catalog product

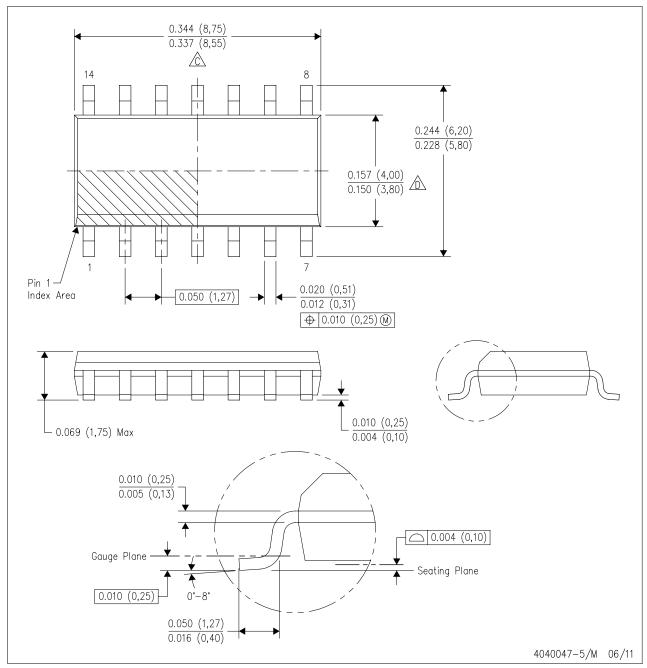
 $_{\bullet}$ Military - QML certified for Military and Defense Applications



MECHANICAL DATA

D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.

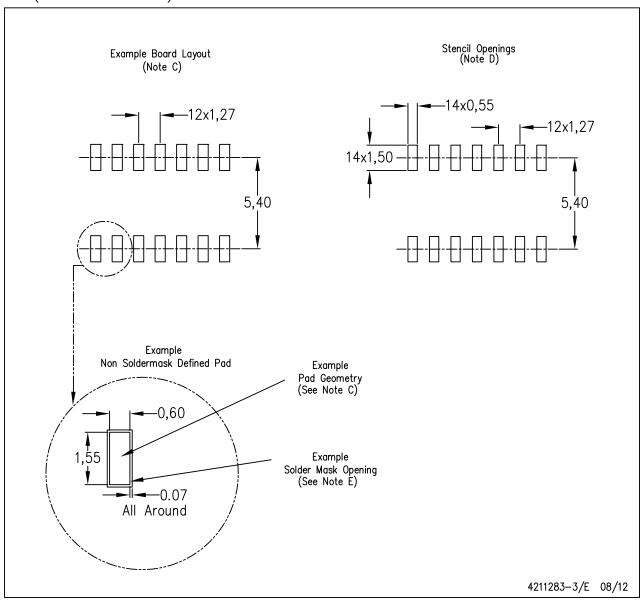




LAND PATTERN DATA

D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.





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